



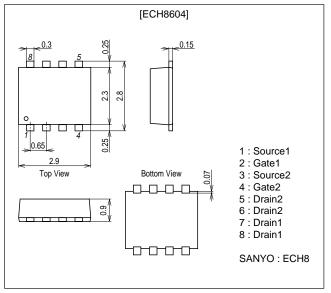
# **Load Switching Applications**

# **Features**

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- · 2.5V drive

# **Package Dimensions**

unit : mm 2206A



# **Specifications**

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		20	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	ID		6	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	40	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm <sup>2</sup> X0.8mm)1unit	1.3	W
Total Dissipation	PT	Mounted on a ceramic board (900mm <sup>2</sup> X0.8mm)	1.5	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	01111
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0	20			V
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =20V, V <sub>GS</sub> =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±8V, V <sub>DS</sub> =0			±10	μΑ
Cutoff Voltage	VGS(off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	0.5		1.3	V

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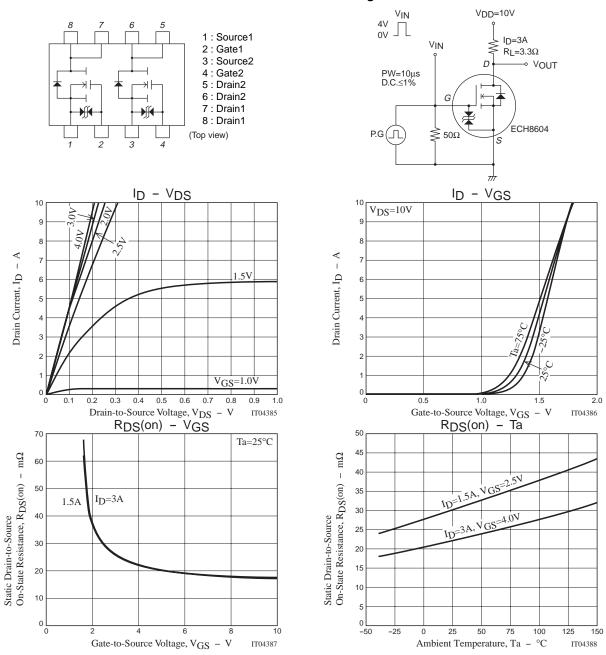
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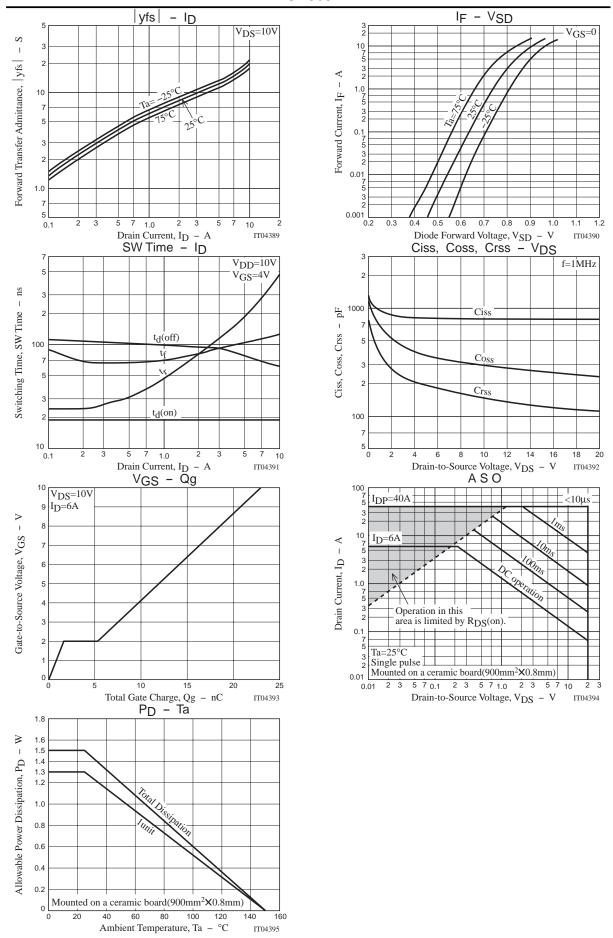
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =3A	7	10		S
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	I <sub>D</sub> =3A, V <sub>GS</sub> =4V		22	30	mΩ
	RDS(on)2	ID=1.5A, VGS=2.5V		30	44	mΩ
Input Capacitance	Ciss	V <sub>DS</sub> =10V, f=1MHz		700		pF
Output Capacitance	Coss	V <sub>DS</sub> =10V, f=1MHz		300		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> =10V, f=1MHz		150		pF
Turn-ON Delay Time	td(on)	See specified Test Circuit.		19		ns
Rise Time	tr	See specified Test Circuit.		134		ns
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.		90		ns
Fall Time	tf	See specified Test Circuit.		94		ns
Total Gate Charge	Qg	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =6A		23		nC
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =6A		1.6		nC
Gate-to-Drain "Miller" Charge	Qgd	V <sub>DS</sub> =10V, V <sub>GS</sub> =10V, I <sub>D</sub> =6A		3.6		nC
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =6A, V <sub>GS</sub> =0		0.84	1.2	V

### **Electrical Connection**

# **Switching Time Test Circuit**



### **ECH8604**



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